VS-12F(R) Series

Vishay Semiconductors



Standard Recovery Diodes, (Stud Version), 12 A



PRIMARY CHARACTERISTICS				
I _{F(AV)} 12 A				
Package DO-4 (DO-203AA)				
Circuit configuration Single				

FEATURES

- High surge current capability
- Stud cathode and stud anode version
- Wide current range
- Types up to 1200 V V_{RRM}
- Designed and qualified for industrial and consumer level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Battery charges
- Converters
- Power supplies
- Machine tool controls

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
		12	A	
I _{F(AV)}	T _C	144	O°	
I _{F(RMS)}		19	A	
IFSM	50 Hz	265	٨	
	60 Hz	280	A	
l ² t	50 Hz	351	A ² s	
1-1	60 Hz	320	A-5	
V _{RRM}	Range	100 to 1200	V	
TJ		-65 to +175	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I _{RBM} MAXIMUM AT T _J = 175 °C mA
	10	100	150	
	20	200	275	
	40	400	500	
VS-12F(R)	60	600	725	12
	80	800	950	
	100	1000	1200	
	120	1200	1400	

Revision: 11-Jan-18

Document Number: 93487

1





www.vishay.com

Vishay Semiconductors

FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average forward current	I _{F(AV)}	180° conduction, half sine wave		12	А	
at case temperature	· (AV)				144	°C
Maximum RMS forward current	I _{F(RMS)}				19	A
		t = 10 ms	No voltage	Sinusoidal half wave,	265	A A ² s
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied		280	
non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{BBM}		225	
		t = 8.3 ms	reapplied		235	
	l ² t	t = 10 ms	No voltage	initial $T_J = T_J$ maximum	351	
Maximum I ² t for fusing		t = 8.3 ms	reapplied	-	320	
		t = 10 ms	100 % V _{RRM}		250	
		t = 8.3 ms	reapplied		226	
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied			3510	A²√s
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum			0.77	v
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi x I_{F(AV)}), T_J = T_J maximum$			0.97	v
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum			10.70	mΩ
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J = T_J maximum$			6.20	11152
Maximum forward voltage drop	V _{FM}	$I_{pk} = 38 \text{ A}, T_J = 25 \text{ °C}, t_p = 400 \mu\text{s} \text{ rectangular wave}$			1.26	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL TEST CONDITIONS		VALUES	UNITS	
Maximum junction operating temperature range	ge T _J		-65 to +175	°C	
Maximum storage temperature range	T _{Stg}		-65 to +200	-C	
Maximum thermal resistance, junction to case	R _{thJC}	R _{thJC} DC operation		K/W	
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.5	r./ VV	
Allowable mounting torque		Not lubricated threads	1.5 + 0 - 10 %	N·m	
			13	lbf ∙ in	
			1.2 + 0 - 10 %	N⋅m	
		Lubricated threads	10	lbf · in	
Approximate weight			7	g	
Approximate weight			0.25	oz.	
Case style		See dimensions - link at the end of datasheet	DO-4 (DO-	-203AA)	

CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.33	0.26			
120°	0.41	0.44			
90°	0.53	0.58	$T_J = T_J maximum$	K/W	
60°	0.78	0.81			
30°	1.28	1.29			

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC



Vishay Semiconductors

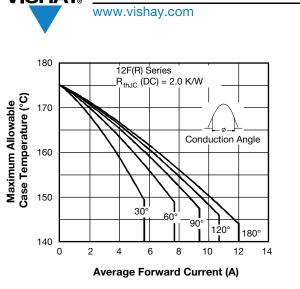


Fig. 1 - Current Ratings Characteristics

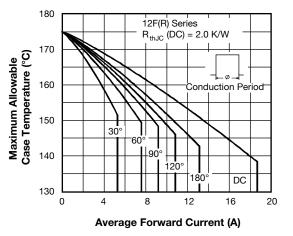


Fig. 2 - Current Ratings Characteristics

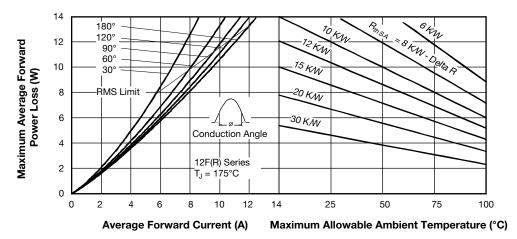
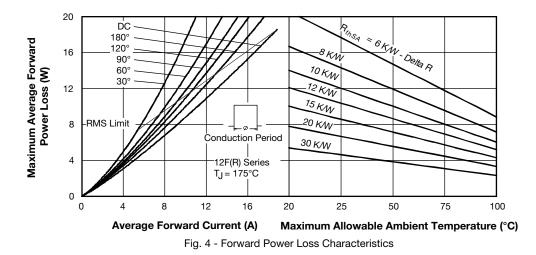
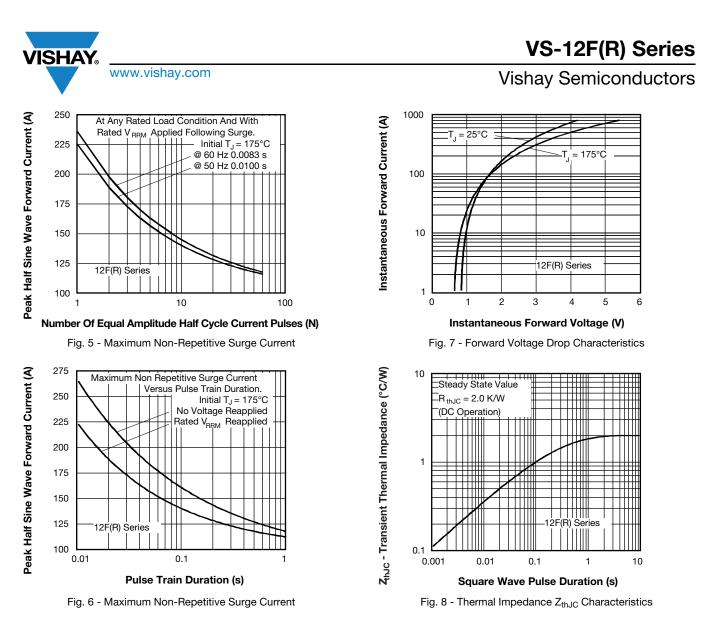
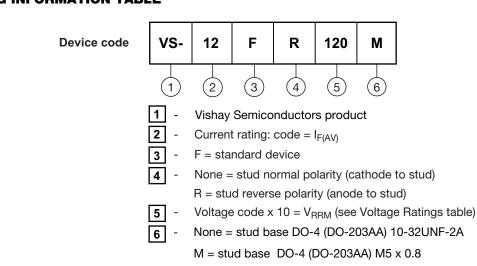


Fig. 3 - Forward Power Loss Characteristics





ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS			
Dimensions		www.vishay.com/doc?95311	
Revision: 11-Jan-18	4	Document Number: 93487	
For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com			

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



Vishay Semiconductors

R 0.40 R (0.02)

Ø 6.8 (0.27)

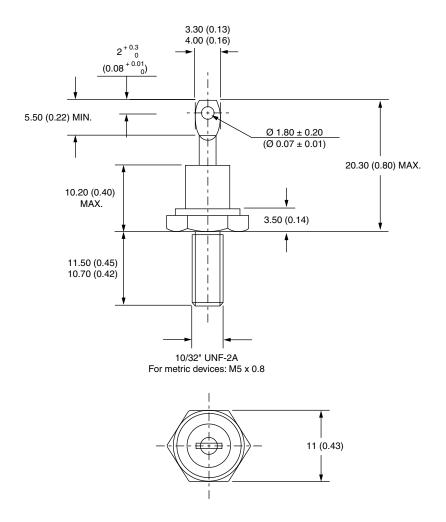
 0.8 ± 0.1

 (0.03 ± 0.004)



DO-203AA (DO-4)

DIMENSIONS in millimeters (inches)







Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by Vishay manufacturer:

Other Similar products are found below :

MA4E2039 D1FH3-5063 MBR10100CT-BP MBR1545CT MMBD301M3T5G RB160M-50TR RB551V-30 BAS16E6433HTMA1 BAT 54-02LRH E6327 NSR05F40QNXT5G NTE555 JANS1N6640 SB07-03C-TB-H SB1003M3-TL-W SK310-T SK32A-LTP SK33A-TP SK34B-TP SS3003CH-TL-E GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRB30H30CT-1G SB007-03C-TB-E SK32A-TP SK33B-TP SK35A-TP SK38B-TP NRVBM120LT1G NTE505 NTSB30U100CT-1G SS15E-TP VS-6CWQ10FNHM3 ACDBA1100LR-HF ACDBA1200-HF ACDBA140-HF ACDBA2100-HF ACDBA3100-HF CDBQC0530L-HF CDBQC0240LR-HF ACDBA340-HF ACDBA260LR-HF ACDBA1100-HF SK310B-TP MA4E2502L-1246 MA4E2502H-1246 NRVBM120ET1G NSR01L30MXT5G NTE573 NTE6081